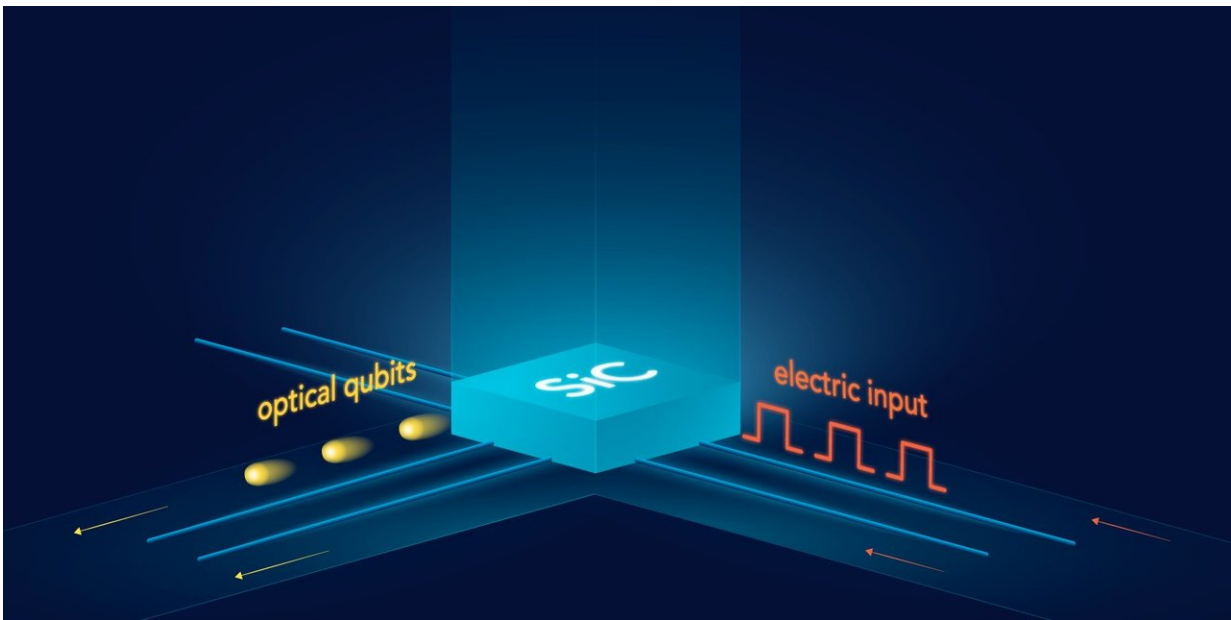


Physicists reveal material for high-speed quantum internet

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Electrical excitation causes a point defect in the crystal lattice of silicon carbide to emit single photons, which are of use to quantum cryptography. Credit: Elena Khavina, MIPT

Researchers from the Moscow Institute of Physics and Technology have rediscovered a material that could be the basis for ultra-high-speed quantum internet. Their paper published in *npj Quantum Information* shows how to increase the data transfer rate in unconditionally secure quantum communication lines to more than one gigabit per second,

making quantum internet as fast as its classical counterpart.

Industry giants including Google, IBM and Microsoft, and leading international research centers and universities, are involved in the global effort to build a [quantum](#) computer. Quantum computers could break the security of all classical [data transfer](#) networks. Today, sensitive data such as personal communications or financial information are protected using encryption algorithms that would take a classical supercomputer years to crack. A quantum computer could conceivably do it in a few seconds.

Luckily, quantum technologies also provide a way of neutralizing this threat. Modern classical cryptographic algorithms are complexity-based, and can remain secure only for a certain period of time. Unlike its classical counterpart, quantum cryptography relies on the fundamental laws of physics, which can guarantee security of data transmission forever. The operation principle is based on the fact that an unknown quantum state cannot be copied without altering the original message. This means that a quantum communication line cannot be compromised without the sender and the receiver knowing. Even a quantum computer would be of no use to eavesdroppers.

Photons, quanta of light, are the best carriers for quantum bits. Only [single photons](#) can be used; otherwise, an eavesdropper might intercept one of the transmitted photons and obtain a copy of the message. The principle of single-[photon](#) generation is quite simple: An excited quantum system can relax into the ground state by emitting exactly one photon. This would require a real-world physical system that reliably generates single photons under ambient conditions. However, such a system is not easy to develop. For example, quantum dots could be a good option, but they only work well when cooled below -200 degrees Celsius, while new two-dimensional materials such as graphene are simply unable to generate single photons at a high repetition rate under electrical excitation.

The MIPT researchers are exploring [silicon carbide](#), a semiconductor material long forgotten in optoelectronics. "In 2014, we were studying diamond, and turned our attention to [silicon](#) carbide almost by accident. We figured it had vast potential," says Dmitry Fedyanin. However, as he explains, electrically driven emission of single photons in this semiconductor was only achieved one year later, in 2015, by an Australian research team.

Surprisingly, silicon carbide is a material that started the whole of optoelectronics: The phenomenon of electroluminescence, in which an electric current causes a material to emit light, was observed for the first time in silicon carbide. In the 1920s, the material was used in the world's first light-emitting diodes (LEDs). In the '70s, silicon carbide LEDs were mass-produced in the Soviet Union. However, after that, silicon carbide lost the battle against direct-bandgap semiconductors and was abandoned by optoelectronics. Nowadays, this material is mostly known for being extremely hard and heat-resistant—it is used in high-power electronics, bulletproof vests, and the brakes of sports cars produced by Porsche, Lamborghini, and Ferrari.

Together with his colleagues, Fedyanin studied the physics of electroluminescence of color centers in silicon carbide and came up with a theory of single-photon emission upon electrical injection that explains and accurately reproduces the experimental findings. A color center is a point defect in the lattice structure of silicon carbide that can emit or absorb a photon at a wavelength to which the material is transparent in the absence of defects. This process is at the heart of the electrically driven single-photon source.

Using their theory, the researchers have shown improved a single-photon emitting diode based on silicon carbide in order to emit up to several billion photons per second. Thus, it is possible to implement [quantum cryptography](#) protocols at data transfer rates on the order of 1 Gbps.

Study co-authors Igor Khramtsov and Andrey Vyshnevyy point out that new [materials](#) are likely to be found that rival silicon carbide in terms of the brightness of single-photon emission. However, unlike silicon carbide, they will require new technological processes to be used in mass production of devices. By contrast, silicon carbide-based single-photon sources are compatible with the CMOS technology, which is a standard for manufacturing electronic integrated circuits. This makes silicon carbide by far the most promising material for building practical ultrawide-bandwidth unconditionally secure data communication lines.

More information: Igor A. Khramtsov et al. Enhancing the brightness of electrically driven single-photon sources using color centers in silicon carbide, *npj Quantum Information* (2018). [DOI: 10.1038/s41534-018-0066-2](#)

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